Green Products

ST10100S SCHOTTKY RECTIFIER

Applications:

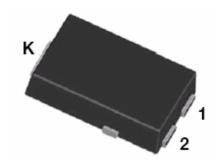
- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

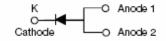
Features:

- 150 °C T_J operation
- Center tap configuration
- Ultralow forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- · Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device

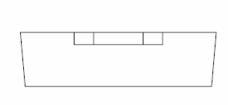
Mechanical Dimensions: In mm

- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request





6. 50 ±0. 20 5. 38 ±0. 10 0. 56 0 0+06 0 0 0+06 0 0 0+06 0



TO-277B

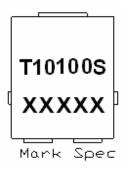
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Marking Diagram:



Where XXXXX is YYWWL

T = Ultralow VF

10 = Forward Current (10) 100 = Reverse Voltage (100V)

S = Package type

YY = Year WW = Week L = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping
ST10100S	TO-277B	F000pag/ rool
	(Pb-Free)	5000pcs/ reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V_{RWM}	-	100	V
Average Forward Current	I _{F(AV)}	50% duty cycle @T _C = 80 °C rectangular wave form	10	А
Peak One Cycle Non- Repetitive Surge Current (per leg)	I _{FSM}	8.3 ms, half Sine pulse	150	А

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Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Forward Voltage Drop*	V_{F1}	@ 10A, Pulse, T _J = 25 °C	0.68	V
	V_{F2}	@ 10A, Pulse, T _J = 125 °C	0.62	V
Reverse Current (per leg)	I _{R1}	$@V_R = \text{rated } V_R$ $T_J = 25 ^{\circ}C$	0.25	mA
Reverse Current (per leg) *	I _{R2}	$@V_R = \text{rated } V_R$ $T_J = 125 ^{\circ}\text{C}$	36	mA
Junction Capacitance (per leg)	Ст	$@V_R = 5V, T_C = 25 \text{ °C}$ $f_{SIG} = 1MHz$	550	pF
Voltage Rate of Change	dv/dt	-	10,000	V/μs

^{*} Pulse Width < 300 μ s, Duty Cycle <2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	T_J	-	-55 to +150	°C
Storage Temperature	T_{stg}	-	-55 to +150	°C
Maximum Thermal Resistance Junction to Ambient	$R_{ heta JA}$	DC operation	60	°C/W
Approximate Weight	wt	-	0.08	g
Case Style		TO-277B		





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